

NPN HIGH VOLTAGE TRANSISTOR **SOT-23** Unit: inch(mm) 300 Volt POWER VOLTAGE 250 mWatt **FEATURES** 0.006(0.15)MIN. 0.120(3.04) • NPN silicon, planar design 0.110(2.80) Collector-emitter voltage V_{CE} = 300V • Collector current $I_c = 500 \text{mA}$ • Lead free in compliance with EU RoHS 2.0 0.103(2.60) 0.086(2.20) • Green molding compound as per IEC 61249 standard 0.056(1.40) 0.047(1.20) 0.079(2.00) 0.008(0.20) 0.070(1.80) 0.003(0.08) **MECHANICAL DATA** · Case: SOT-23, Plastic 0.004(0.10) 0.044(1.10) 0.000(0.00) 0.035(0.90) • Terminals: Solderable per MIL-STD-750, Method 2026

0.020(0.50)

0.013(0.35)

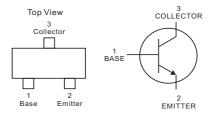
- Approx weight: 0.0003 ounces, 0.0084 grams
- Marking: A42

ABSOLUTE MAXIMUM RATINGS

PARAMETER	Symbol	Value	Units
Collector - Emitter Voltage	V _{ceo}	300	V
Collector - Base Voltage	V _{сво}	300	V
Emitter - Base Voltage	V _{ebo}	6	V
Collector Current Continuous	I _c	500	mA

THERMAL CHARACTERISTICS

PARAMETER	Symbol	Value	Units
Max Power Dissipation (Note 1)	P _{TOT}	250	mW
Thermal Resistance, Junction to Ambient	R _{eja}	500	°C/W
Junction Temperature	TJ	-55 to 150	°C
Storage Temperature	T _{stg}	-55 to 150	°C



Note 1 : Transistor mounted on FR-5 board 1 x 0.75 x 0.062 in.



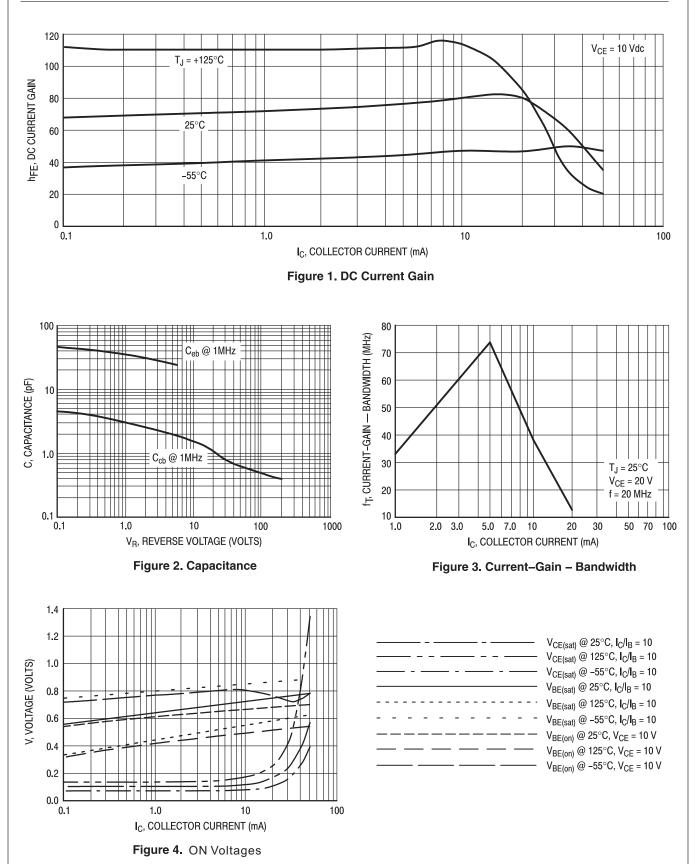
ELECTRICAL CHARACTERISTICS

PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	V _(BR) CEO	$I_{c}=1 \text{ mA}, I_{B}=0$	300	-	-	V
Collector - Base Breakdown Voltage	V _(BR) CBO	$I_{c} = 100 \mu A, I_{E} = 0$	300	-	-	V
Emitter - Base Breakdown Voltage	V _(BR) EBO	$I_{E} = 100 \mu A, I_{C} = 0$	6	-	-	V
Collector Cut-off Current	І _{сво}	V _{CB} =200V,I _E =0V	-	-	100	nA
Emitter Cut-off Current	I _{EBO}	V _{CE} =6V,I _C =0	-	-	100	nA
DC Current Gain	h _{FE}	$V_{cE} = 10V,I_{c} = 1.0mA$ $V_{cE} = 10V,I_{c} = 10mA$ $V_{cE} = 10V,I_{c} = 30mA$	25 40 40	- -	- -	-
Collector - Emitter Saturation Voltage	V _{ce(sat)}	I _c =20mA,I _B =2mA	-	-	0.5	V
Base - Emitter Satruation Voltage	V _{BE(SAT)}	I _c =20mA,I _B =2mA	-	-	0.9	V
Collector-Base Capacitance	С _{сво}	$V_{CB}=20V,I_{E}=0,f=1MHz$	-	-	3	pF
Collector Gain - Bandwidth Product	F _T	I _c =10mA,V _{CE} =20V f=100MH _z	50	-	-	MHz





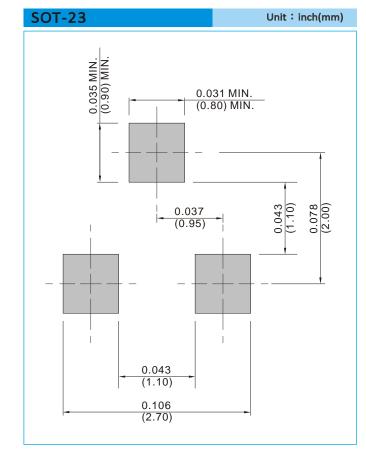
ELECTRICAL CHARACTERISTICS CURVE



- 63



MOUNTING PAD LAYOUT



ORDER INFORMATION

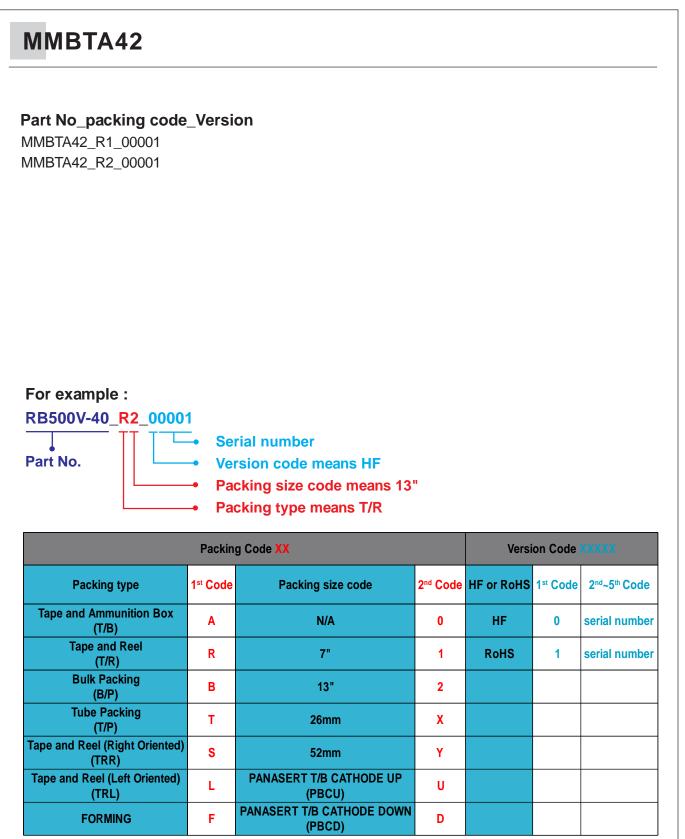
• Packing information

T/R - 12K per 13" plastic Reel

T/R - 3K per 7" plastic Reel

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